

# HI-546, HI-547 HI-548, HI-549

## Single 16 and 8, Differential 8 and 4 Channel CMOS Analog MUXs with Active Overvoltage Protection

December 1993

### Features

- Analog Overvoltage Protection.....70V<sub>P.P</sub>
- No Channel Interaction During Overvoltage
- Guaranteed R<sub>ON</sub> Matching
- 44V Maximum Power Supply
- Break-Before-Make Switching
- Analog Signal Range.....±15V
- Access Time (Typical) ..... 500ns
- Standby Power (Typical) .....7.5mW

### Applications

- Data Acquisition
- Industrial Controls
- Telemetry

### Description

The HI-546, HI-547, HI-548 and HI-549 are analog multiplexers with active overvoltage protection and guaranteed RON matching. Analog input levels may greatly exceed either power supply without damaging the device or disturbing the signal path of other channels. Active protection circuitry assures that signal fidelity is maintained even under fault conditions that would destroy other multiplexers.

Analog inputs can withstand constant 70V<sub>P.P</sub> levels with ±15V supplies. Digital inputs will also sustain continuous faults up to 4V greater than either supply. In addition, signal sources are protected from short circuiting should multiplexer supply loss occur. Each input presents 1KΩ of resistance under this condition. These features make the HI-546, HI-547, HI-548 and HI-549 ideal for use in systems where the analog inputs originate from external equipment or separately powered circuitry. All devices are fabricated with 44V Dielectrically Isolated CMOS technology. The HI-546 is a single 16 channel, the HI-547 is an 8 channel differential, the HI-548 is a single 8 channel and the HI-549 is a 4 channel differential device. If input overvoltage protection is not needed the HI-506/507/508/509 multiplexers are recommended. For further information see Application Notes 520 and 521. The HI-546 and HI-547 devices are available in a 28 lead Plastic or Ceramic DIP and a 28 pad Ceramic LCC package. The HI-548/549 devices are available in a 16 lead Plastic or Ceramic DIP and a 20 pad Ceramic LCC package.

The HI-546, HI-547, HI-548 and HI-549 are offered in industrial/commercial and military grades. Additional Hi-Rel screening including 160 hour Bum-In is specified by the "-8" suffix. For Mil-Std-883 compliant parts, request the HI-546/883, HI-547/883, HI-548/883 and HI-549/883 datasheets.

### Ordering Information

| PART NUMBER  | TEMPERATURE RANGE | PACKAGE              |
|--------------|-------------------|----------------------|
| HI1-0546-4   | -25°C to +85°C    | 28 Lead Ceramic DIP  |
| HI1-0546-5   | 0°C to +75°C      | 28 Lead Ceramic DIP  |
| HI1-0546-2   | -55°C to +125°C   | 28 Lead Ceramic DIP  |
| HI1-0546/883 | -55°C to +125°C   | 28 Lead Ceramic DIP  |
| HI3-0546-5   | 0°C to +75°C      | 28 Lead Plastic DIP  |
| HI3-0546-9   | -40°C to +85°C    | 28 Lead Plastic DIP  |
| HI4-0546/883 | -55°C to +125°C   | 28 Lead Ceramic LCC  |
| HI4P0546-5   | 0°C to +75°C      | 28 Lead PLCC         |
| HI9P0546-5   | 0°C to +75°C      | 28 Lead Plastic SOIC |
| HI9P0546-9   | -40°C to +85°C    | 28 Lead Plastic SOIC |
| HI1-0547-2   | -55°C to +125°C   | 28 Lead Ceramic DIP  |
| HI1-0547-4   | -25°C to +85°C    | 28 Lead Ceramic DIP  |

| PART NUMBER  | TEMPERATURE RANGE | PACKAGE              |
|--------------|-------------------|----------------------|
| HI1-0547-5   | 0°C to +75°C      | 28 Lead Ceramic DIP  |
| HI1-0547-9   | -40°C to +85°C    | 28 Lead Ceramic DIP  |
| HI1-0547/883 | -55°C to +125°C   | 28 Lead Ceramic DIP  |
| HI3-0547-5   | 0°C to +75°C      | 28 Lead Plastic DIP  |
| HI3-0547-9   | -40°C to +85°C    | 28 Lead Plastic DIP  |
| HI4-0547/883 | -55°C to +125°C   | 28 Lead Ceramic LCC  |
| HI4P0547-5   | 0°C to +75°C      | 28 Lead PLCC         |
| HI9P0547-5   | 0°C to +75°C      | 28 Lead Plastic SOIC |
| HI9P0547-9   | -40°C to +85°C    | 28 Lead Plastic SOIC |

# Ordering Information (Continued)

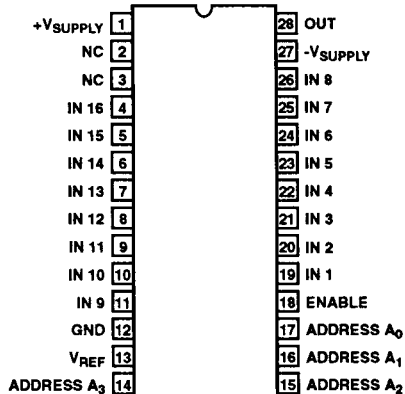
| PART NUMBER  | TEMPERATURE RANGE | PACKAGE              |
|--------------|-------------------|----------------------|
| HI1-0548-2   | -55°C to +125°C   | 16 Lead Ceramic DIP  |
| HI1-0548-4   | -25°C to +85°C    | 16 Lead Ceramic DIP  |
| HI1-0548-5   | 0°C to +75°C      | 16 Lead Ceramic DIP  |
| HI1-0548/883 | -55°C to +125°C   | 16 Lead Ceramic DIP  |
| HI3-0548-5   | 0°C to +75°C      | 16 Lead Plastic DIP  |
| HI3-0548-9   | -40°C to +85°C    | 16 Lead Plastic DIP  |
| HI4-0548/883 | -55°C to +125°C   | 20 Lead Ceramic LCC  |
| HI4P0548-5   | 0°C to +75°C      | 20 Lead Plastic LCC  |
| HI9P0548-5   | 0°C to +75°C      | 16 Lead Plastic SOIC |
| HI9P0548-9   | -40°C to +85°C    | 16 Pin SOIC (W)      |

| PART NUMBER  | TEMPERATURE RANGE | PACKAGE              |
|--------------|-------------------|----------------------|
| HI1-0549-2   | -55°C to +125°C   | 16 Lead Ceramic DIP  |
| HI1-0549-4   | -25°C to +85°C    | 16 Lead Ceramic DIP  |
| HI1-0549-5   | 0°C to +75°C      | 16 Lead Ceramic DIP  |
| HI1-0549/883 | -55°C to +125°C   | 16 Lead Ceramic DIP  |
| HI3-0549-5   | 0°C to +75°C      | 16 Lead Plastic DIP  |
| HI3-0549-9   | -40°C to +85°C    | 16 Lead Plastic DIP  |
| HI4-0549/883 | -55°C to +125°C   | 20 Lead Ceramic LCC  |
| HI4P0549-5   | 0°C to +75°C      | 20 Lead Plastic LCC  |
| HI9P0549-5   | 0°C to +75°C      | 20 Lead Plastic SOIC |
| HI9P0549-9   | -40°C to +85°C    | 16 Pin SOIC (W)      |

## Pinouts

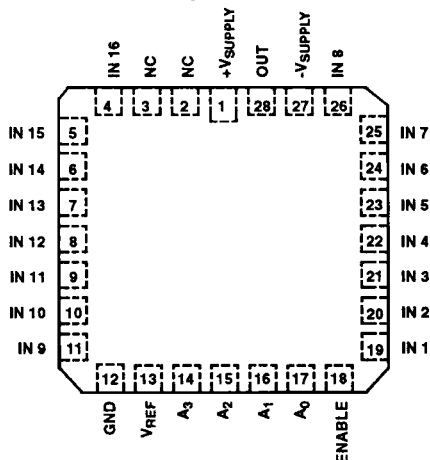
HI1-0546 (CDIP), HI3-0546 (PDIP), HI9P0546 (SOIC)

TOP VIEW



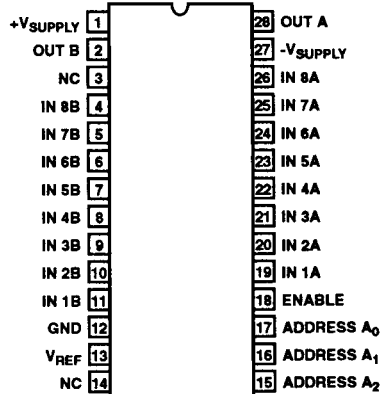
HI4P0546 (PLCC)

TOP VIEW



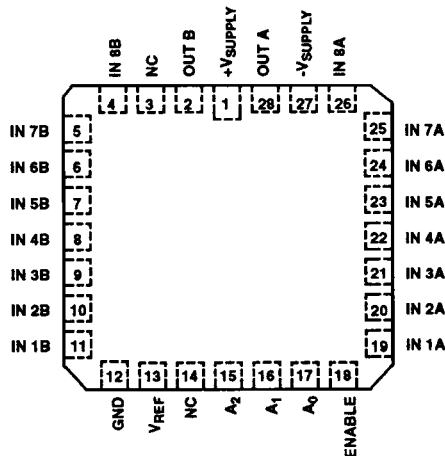
HI1-0547 (CDIP), HI3-0547 (PDIP), HI9P0547 (SOIC)

TOP VIEW



HI4P0547 (PLCC)

TOP VIEW

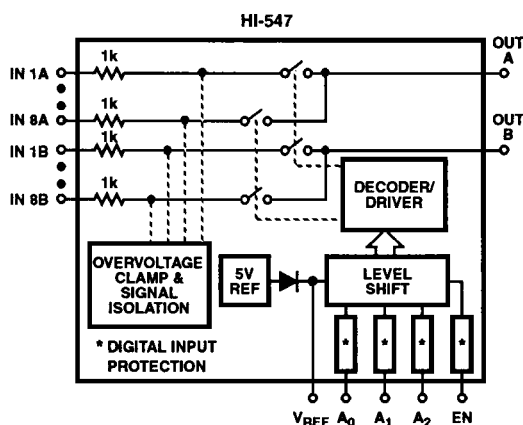


### ***Pinouts* (Continued)**

|                            |          |           |                            |
|----------------------------|----------|-----------|----------------------------|
| <b>A<sub>0</sub></b>       | <b>1</b> | <b>16</b> | <b>A<sub>1</sub></b>       |
| <b>ENABLE</b>              | <b>2</b> | <b>15</b> | <b>A<sub>2</sub></b>       |
| <b>-V<sub>SUPPLY</sub></b> | <b>3</b> | <b>14</b> | <b>GND</b>                 |
| <b>IN 1</b>                | <b>4</b> | <b>13</b> | <b>+V<sub>SUPPLY</sub></b> |
| <b>IN 2</b>                | <b>5</b> | <b>12</b> | <b>IN 5</b>                |
| <b>IN 3</b>                | <b>6</b> | <b>11</b> | <b>IN 6</b>                |
| <b>IN 4</b>                | <b>7</b> | <b>10</b> | <b>IN 7</b>                |
| <b>OUT</b>                 | <b>8</b> | <b>9</b>  | <b>IN 8</b>                |

|                      |   |    |                      |
|----------------------|---|----|----------------------|
| A <sub>0</sub>       | 1 | 16 | A <sub>1</sub>       |
| ENABLE               | 2 | 15 | GND                  |
| -V <sub>SUPPLY</sub> | 3 | 14 | +V <sub>SUPPLY</sub> |
| IN 1A                | 4 | 13 | IN 1B                |
| IN 2A                | 5 | 12 | IN 2B                |
| IN 3A                | 6 | 11 | IN 3B                |
| IN 4A                | 7 | 10 | IN 4B                |
| OUT A                | 8 | 9  | OUT B                |

The diagram shows a circuit labeled HI-546. It features a 5V REF input connected to a LEVEL SHIFT block. The LEVEL SHIFT block has four outputs labeled A<sub>0</sub>, A<sub>1</sub>, A<sub>2</sub>, and A<sub>3</sub>, each with an asterisk. These outputs are connected to the DECODER/ DRIVER block. The DECODER/ DRIVER block has 16 digital inputs labeled IN 1, IN 2, and IN 16, each with a 1k resistor and a switch. The DECODER/ DRIVER block also has an output labeled OUT. An OVERVOLTAGE CLAMP & SIGNAL ISOLATION block is connected to the input lines. A note at the bottom states: \* DIGITAL INPUT PROTECTION.



**HI-549**

IN 1A  
IN 4A  
IN 1B  
IN 4B

1k  
1k  
1k  
1k

OVERVOLTAGE CLAMP & SIGNAL ISOLATION

\* DIGITAL INPUT PROTECTION

5V REF

DECODER/ DRIVER

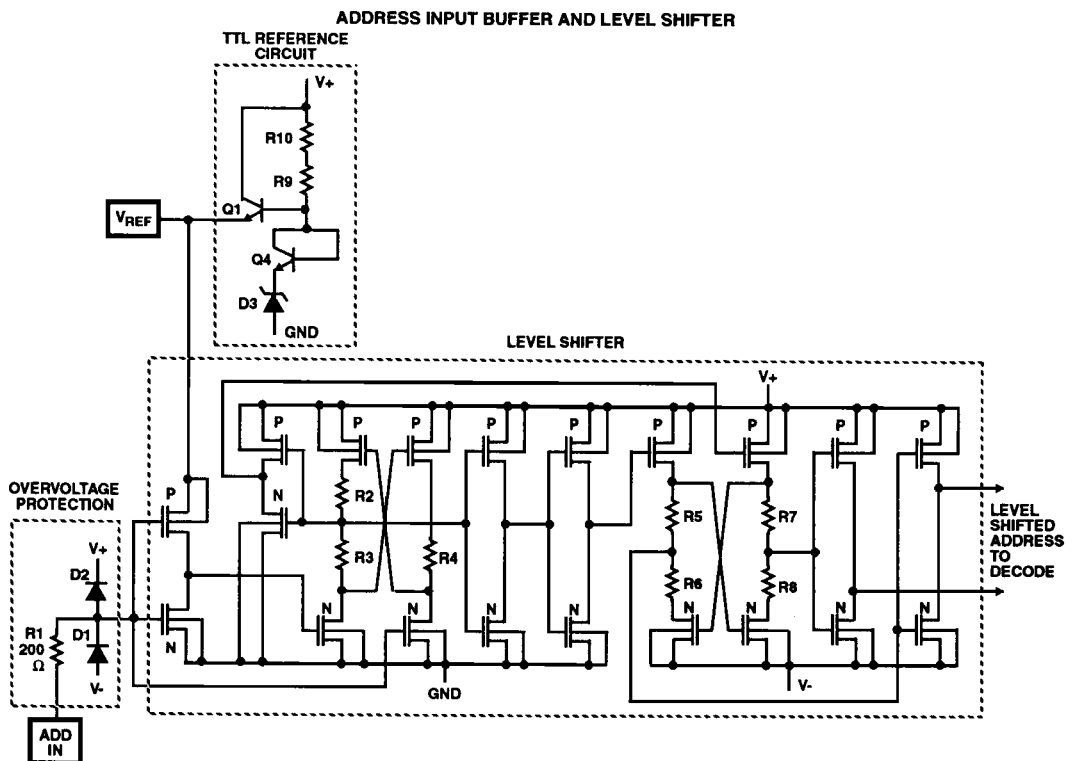
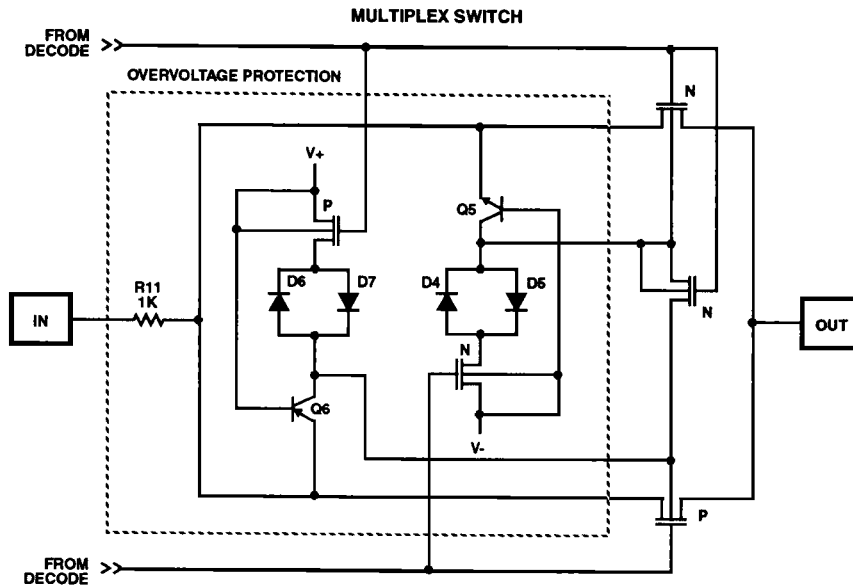
LEVEL SHIFT

OUT A  
OUT B

A<sub>0</sub>  
A<sub>1</sub>  
EN

The diagram shows the internal structure of a 4-to-1 multiplexer. It consists of a top row of P-channel MOSFETs and a bottom row of N-channel MOSFETs. The gates of the P-channel MOSFETs are connected to a common +V supply. The gates of the N-channel MOSFETs are connected to a common -V supply. The sources of all P-channel MOSFETs are connected to a common output node labeled "TO P-CHANNEL DEVICE OF THE SWITCH". The sources of all N-channel MOSFETs are connected to a common output node labeled "TO N-CHANNEL DEVICE OF THE SWITCH". The drains of the P-channel MOSFETs are connected to the drains of the N-channel MOSFETs. The inputs  $A_0$  or  $\bar{A}_0$ ,  $A_1$  or  $\bar{A}_1$ ,  $A_2$  or  $\bar{A}_2$ , and  $A_3$  or  $\bar{A}_3$  are connected to the gates of the N-channel MOSFETs. An "ENABLE" input is connected to the gates of the P-channel MOSFETs. The diagram also shows a +V supply and a -V supply.

**Schematic Diagrams** (Continued)



# Specifications HI-546, HI-547, HI-548, HI-549

## Absolute Maximum Ratings

|                                           |                                     |
|-------------------------------------------|-------------------------------------|
| $V_{SUPPLY(+)} \text{ to } V_{SUPPLY(-)}$ | +44V                                |
| $V_{SUPPLY(+)} \text{ to GND}$            | +22V                                |
| $V_{SUPPLY(-)} \text{ to GND}$            | -25V                                |
| Digital Input Overvoltage                 |                                     |
| $+V_{EN}, +V_A$                           | + $V_{SUPPLY}$ +4V                  |
| $-V_{EN}, -V_A$                           | - $V_{SUPPLY}$ -4V                  |
|                                           | or 20mA, whichever occurs first     |
| Analog Signal Overvoltage (Note 6)        |                                     |
| $+V_S$                                    | + $V_{SUPPLY}$ +20V                 |
| $-V_S$                                    | - $V_{SUPPLY}$ -20V                 |
| Continuous Current, S or D                | 20mA                                |
| Peak Current, S or D                      | 40mA                                |
|                                           | (Pulsed at 1ms, 10% duty cycle max) |
| Storage Temperature Range                 | -65°C to +150°C                     |
| Lead Temperature (Soldering 10s)          | +300°C                              |

## Thermal Information

| Thermal Resistance           | $\theta_{JA}$   | $\theta_{JC}$ |
|------------------------------|-----------------|---------------|
| Ceramic Packages             |                 |               |
| 16 Lead DIP                  | 80°C/W          | 24°C/W        |
| 28 Lead DIP                  | 55°C/W          | 20°C/W        |
| 20 Lead LCC                  | 75°C/W          | 20°C/W        |
| 28 Lead LCC                  | 60°C/W          | 11°C/W        |
| Plastic DIP Packages         |                 |               |
| 28 Lead                      | 60°C/W          | -             |
| 16 Lead                      | 100°C/W         | -             |
| Plastic PLCC Packages        |                 |               |
| 28 Lead                      | 70°C/W          | -             |
| 20 Lead                      | 80°C/W          | -             |
| SOIC                         |                 |               |
| 28 Lead                      | 70°C/W          | -             |
| 16 Lead                      | 100°C/W         | -             |
| Operating Temperature Ranges |                 |               |
| HI-546/547/548/549-2         | -55°C to +125°C |               |
| HI-546/547/548/549-4         | -25°C to +85°C  |               |
| HI-546/547/548/549-5, -7     | 0°C to +75°C    |               |
| HI-546/547/548/549-9         | -40°C to +85°C  |               |
| Junction Temperature         |                 |               |
| Ceramic Package              | +175°C          |               |
| Plastic Package              | +150°C          |               |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

**Electrical Specifications** Supplies = +15V, -15V;  $V_{REF}$  Pin = Open;  $V_{AH}$  (Logic Level High) = +4V;  $V_{AL}$  (Logic Level Low) = +0.8V; Unless Otherwise Specified. For Test Conditions, Consult Performance Curves.

| PARAMETER                                  | TEST<br>CONDITION | TEMP  | HI-54X-2 |     |      | HI-54X-4, -5, -9 |     |      | UNITS |
|--------------------------------------------|-------------------|-------|----------|-----|------|------------------|-----|------|-------|
|                                            |                   |       | MIN      | TYP | MAX  | MIN              | TYP | MAX  |       |
| SWITCHING CHARACTERISTICS                  |                   |       |          |     |      |                  |     |      |       |
| Access Time, $t_A$                         |                   | +25°C | -        | 0.5 | -    | -                | 0.5 | -    | μs    |
|                                            |                   | Full  | -        | -   | 1.0  | -                | -   | 1.0  | μs    |
| Break-Before Make Delay, $t_{OPEN}$        |                   | +25°C | 25       | 80  | -    | 25               | 80  | -    | ns    |
| Enable Delay (ON), $t_{ON(EN)}$            |                   | +25°C | -        | 300 | 500  | -                | 300 | -    | ns    |
|                                            |                   | Full  | -        | -   | 1000 | -                | -   | 1000 | ns    |
| Enable Delay (OFF), $t_{OFF(EN)}$          |                   | +25°C | -        | 300 | 500  | -                | 300 | -    | ns    |
|                                            |                   | Full  | -        | -   | 1000 | -                | -   | 1000 | ns    |
| Settling Time (0.1%)<br>(0.01%)            |                   | +25°C | -        | 1.2 | -    | -                | 1.2 | -    | μs    |
|                                            |                   | +25°C | -        | 3.5 | -    | -                | 3.5 | -    | μs    |
| "Off Isolation"                            | Note 5            | +25°C | 50       | 68  | -    | 50               | 68  | -    | dB    |
| Channel Input Capacitance, $C_{S(OFF)}$    |                   | +25°C | -        | 5   | -    | -                | 5   | -    | pF    |
| Channel Output Capacitance $C_{D(OFF)}$    |                   |       |          |     |      |                  |     |      |       |
| HI-546                                     |                   | +25°C | -        | 52  | -    | -                | 52  | -    | pF    |
| HI-547                                     |                   | +25°C | -        | 30  | -    | -                | 30  | -    | pF    |
| HI-548                                     |                   | +25°C | -        | 25  | -    | -                | 25  | -    | pF    |
| HI-549                                     |                   | +25°C | -        | 12  | -    | -                | 12  | -    | pF    |
| Input to Output Capacitance, $C_{DS(OFF)}$ |                   | +25°C | -        | 0.1 | -    | -                | 0.1 | -    | pF    |

## Specifications HI546, HI-547, HI-548, HI-549

**Electrical Specifications** Supplies = +15V, -15V;  $V_{REF}$  Pin = Open;  $V_{AH}$  (Logic Level High) = +4V;  $V_{AL}$  (Logic Level Low) = +0.8V; Unless Otherwise Specified. For Test Conditions, Consult Performance Curves. (Continued)

| PARAMETER                                                                 | TEST<br>CONDITION | TEMP  | HI-54X-2 |      |     | HI-54X-4, -5, -9 |      |     | UNITS |
|---------------------------------------------------------------------------|-------------------|-------|----------|------|-----|------------------|------|-----|-------|
|                                                                           |                   |       | MIN      | TYP  | MAX | MIN              | TYP  | MAX |       |
| DIGITAL INPUT CHARACTERISTICS                                             |                   |       |          |      |     |                  |      |     |       |
| Input Low Threshold, TTL Drive, $V_{AL}$                                  |                   | Full  | -        | -    | 0.8 | -                | -    | 0.8 | V     |
| Input High Threshold, $V_{AH}$                                            | Note 7            | Full  | 4.0      | -    | -   | 4.0              | -    | -   | V     |
| MOS Drive (HI-546/547 Only), $V_{AL}$                                     | Note 8            | +25°C | -        | -    | 0.8 | -                | -    | 0.8 | V     |
| MOS Drive (HI-546/547 Only), $V_{AH}$                                     | Note 8            | +25°C | 6.0      | -    | -   | 6.0              | -    | -   | V     |
| Input Leakage Current (High or Low), $I_A$                                | Note 4            | Full  | -        | -    | 1.0 | -                | -    | 1.0 | μA    |
| ANALOG CHANNEL CHARACTERISTICS                                            |                   |       |          |      |     |                  |      |     |       |
| Analog Signal Range, $V_S$                                                |                   | Full  | -15      | -    | +15 | -15              | -    | +15 | V     |
| On Resistance, $R_{ON}$                                                   | Note 1            | +25°C | -        | 1.2  | 1.5 | -                | 1.5  | 1.8 | kΩ    |
|                                                                           |                   | Full  | -        | 1.5  | 1.8 | -                | 1.8  | 2.0 | kΩ    |
| $\Delta R_{ON}$ , (Any Two Channels)                                      |                   | +25°C | -        | -    | 7.0 | -                | -    | 7.0 | %     |
| Off Input Leakage Current, $I_{S(OFF)}$                                   | Note 2            | +25°C | -        | 0.03 | -   | -                | 0.03 | -   | nA    |
|                                                                           |                   | Full  | -        | -    | 50  | -                | -    | 50  | nA    |
| Off Output Leakage Current, $I_{D(OFF)}$                                  | Note 2            | +25°C | -        | 0.1  | -   | -                | 0.1  | -   | nA    |
| HI-546                                                                    |                   | Full  | -        | -    | 300 | -                | -    | 300 | nA    |
| HI-547                                                                    |                   | Full  | -        | -    | 200 | -                | -    | 200 | nA    |
| HI-548                                                                    |                   | Full  | -        | -    | 200 | -                | -    | 200 | nA    |
| HI-549                                                                    |                   | Full  | -        | -    | 100 | -                | -    | 100 | nA    |
|                                                                           |                   | Full  | -        | -    | 100 | -                | -    | 100 | nA    |
| With Input Overvoltage Applied, $I_{D(OFF)}$                              | Note 3            | +25°C | -        | 4.0  | -   | -                | 4.0  | -   | nA    |
|                                                                           |                   | Full  | -        | -    | 2.0 | -                | -    | -   | μA    |
| On Channel Leakage Current, $I_{D(ON)}$                                   | Note 2            | +25°C | -        | 0.1  | -   | -                | 0.1  | -   | nA    |
| HI-546                                                                    |                   | Full  | -        | -    | 300 | -                | -    | 300 | nA    |
| HI-547                                                                    |                   | Full  | -        | -    | 200 | -                | -    | 200 | nA    |
| HI-548                                                                    |                   | Full  | -        | -    | 200 | -                | -    | 200 | nA    |
| HI-549                                                                    |                   | Full  | -        | -    | 100 | -                | -    | 100 | nA    |
|                                                                           |                   | Full  | -        | -    | 100 | -                | -    | 100 | nA    |
| Differential Off Output Leakage Current (HI-547, HI-549 Only), $I_{DIFF}$ |                   | Full  | -        | -    | 50  | -                | -    | 50  | nA    |
| POWER REQUIREMENTS                                                        |                   |       |          |      |     |                  |      |     |       |
| Power Dissipation, $P_D$                                                  |                   | Full  | -        | 7.5  | -   | -                | 7.5  | -   | mW    |
| Current, $I_+$                                                            | Note 6            | Full  | -        | 0.5  | 2.0 | -                | 0.5  | 2.0 | mA    |
| Current, $I_-$                                                            | Note 6            | Full  | -        | 0.02 | 1.0 | -                | 0.02 | 1.0 | mA    |

**NOTES:**

- $V_{OUT} = \pm 10V$ ,  $I_{OUT} = \pm 100\mu A$ .
- 10nA is the practical lower limit for high speed measurement in the production test environments.
- Analog Overvoltage =  $\pm 33V$ .
- Digital input leakage is primarily due to the clamp diodes (see Schematic). Typical leakage is less than 1nA at +25°C.
- $V_{EN} = 0.8V$ ,  $R_L = 1K$ ,  $C_L = 15pF$ ,  $V_S = 7V_{RMS}$ ,  $f = 100kHz$ .
- $V_{EN}$ ,  $V_A = 0V$  or 4.0V.
- To drive from DTL/TTL Circuits, 1k $\Omega$  pull-up resistors to +5.0V<sub>SUPPLY</sub> are recommended.
- $V_{REF} = +10V$ .

**Performance Curves**  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$ ,  $V_{\text{AH}} = +4\text{V}$ ,  $V_{\text{AL}} = 0.8\text{V}$ ,  $V_{\text{REF}} = \text{Open}$ , Unless Otherwise Specified

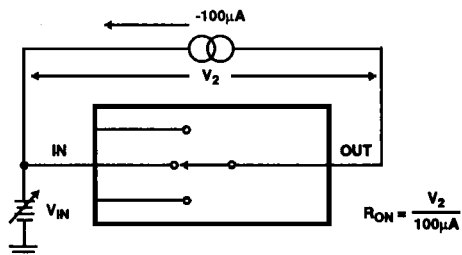


FIGURE 1A. ON RESISTANCE TEST CIRCUIT

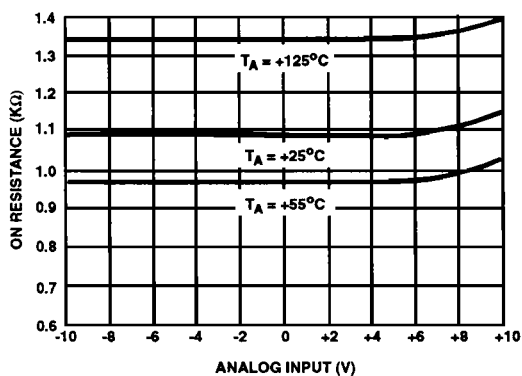


FIGURE 1B. ON RESISTANCE vs ANALOG INPUT VOLTAGE

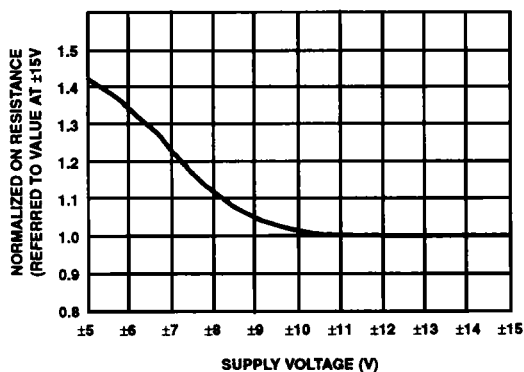


FIGURE 1C. NORMALIZED ON RESISTANCE vs SUPPLY VOLTAGE

FIGURE 1. ON RESISTANCE

**Performance Curves**  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$ ,  $V_{\text{AH}} = +4\text{V}$ ,  $V_{\text{AL}} = 0.8\text{V}$ ,  $V_{\text{REF}} = \text{Open}$ , Unless Otherwise Specified  
(Continued)

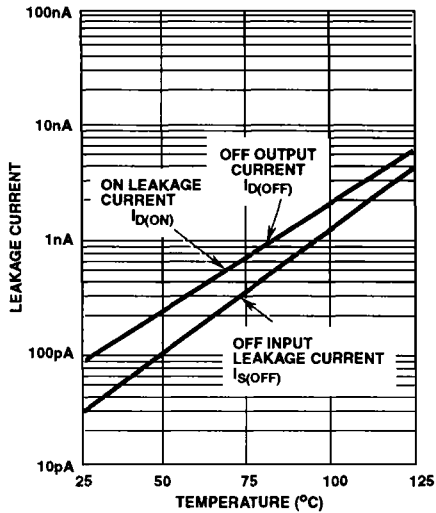


FIGURE 2A. LEAKAGE CURRENT vs TEMPERATURE

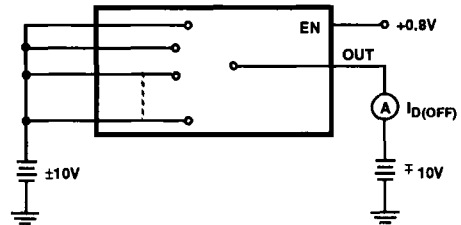


FIGURE 2B.  $I_{D(OFF)}$  TEST CIRCUIT

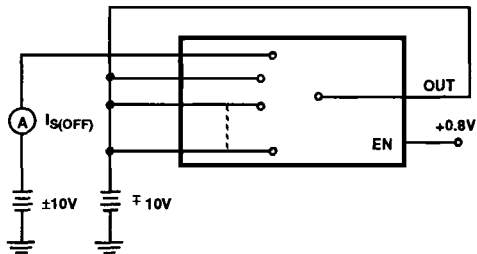


FIGURE 2C.  $I_{S(OFF)}$  TEST CIRCUIT

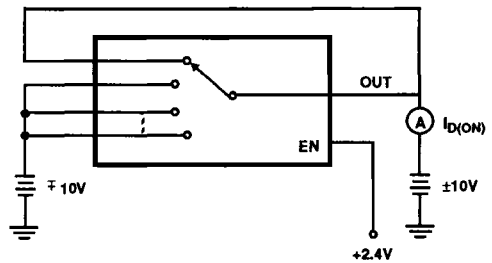


FIGURE 2D.  $I_{D(ON)}$  TEST CIRCUIT

**FIGURE 2. LEAKAGE CURRENT**

**NOTE:**

1. Two measurements per channel:  $+10\text{V}/-10\text{V}$  and  $-10\text{V}/+10\text{V}$ . (Two measurements per device for  $I_{D(OFF)}$ :  $+10\text{V}/-10\text{V}$  and  $-10\text{V}/+10\text{V}$ )

**Performance Curves**  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$ ,  $V_{\text{AH}} = +4\text{V}$ ,  $V_{\text{AL}} = 0.8\text{V}$ ,  $V_{\text{REF}} = \text{Open}$ , Unless Otherwise Specified  
(Continued)

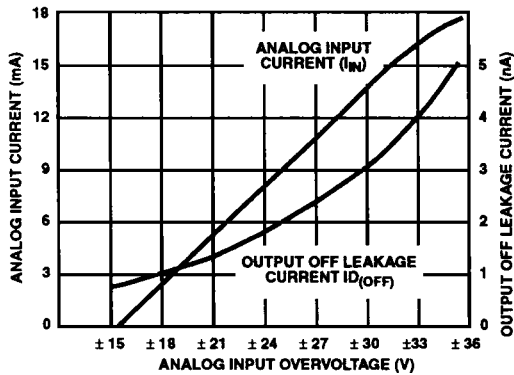


FIGURE 3A. ANALOG INPUT CURRENT AND OUTPUT OFF LEAKAGE CURRENT vs ANALOG INPUT OVERVOLTAGE

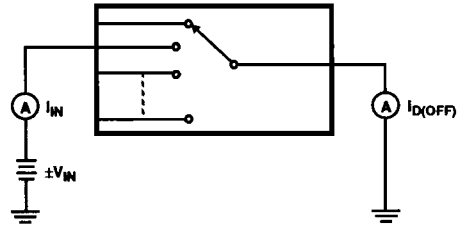


FIGURE 3B. ANALOG INPUT OVERVOLTAGE TEST CIRCUIT

FIGURE 3. ANALOG INPUT OVERVOLTAGE CHARACTERISTICS

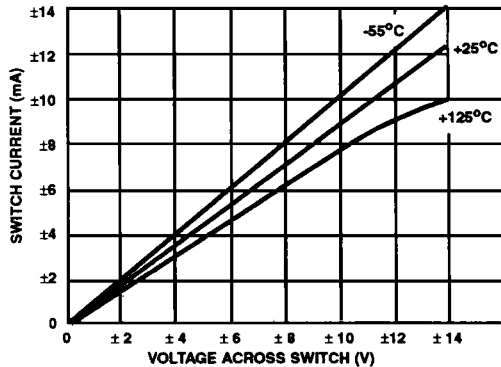


FIGURE 4A. ON CHANNEL CURRENT vs VOLTAGE

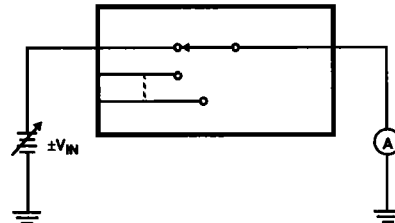


FIGURE 4B. ON CHANNEL CURRENT TEST CIRCUIT

FIGURE 4. ON CHANNEL CURRENT

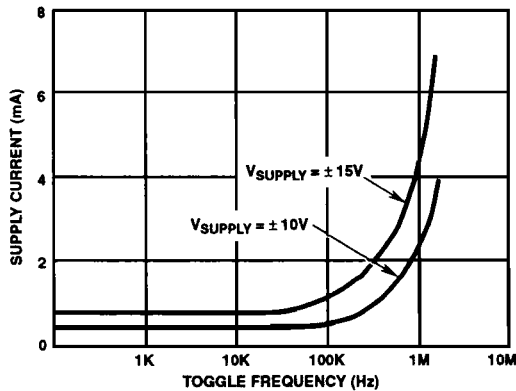
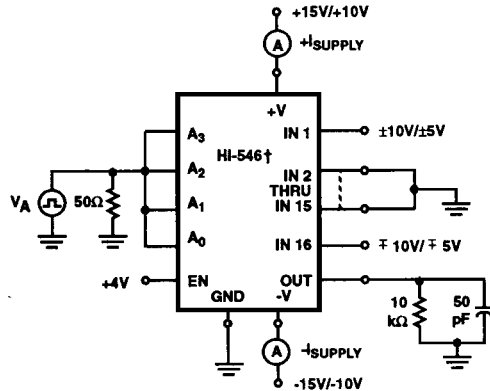


FIGURE 5A. SUPPLY CURRENT vs TOGGLE FREQUENCY



†Similar connection for HI-547/HI-548/HI-549

FIGURE 5B. SUPPLY CURRENT vs TOGGLE FREQUENCY

FIGURE 5. SUPPLY CURRENT

# HI-546, HI-547, HI-548, HI-549

**Performance Curves**  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$ ,  $V_{\text{AH}} = +4\text{V}$ ,  $V_{\text{AL}} = 0.8\text{V}$ ,  $V_{\text{REF}} = \text{Open}$ , Unless Otherwise Specified  
(Continued)

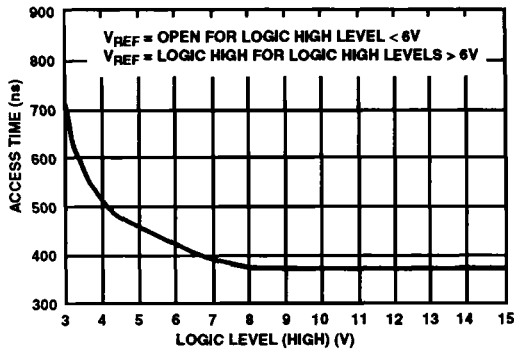
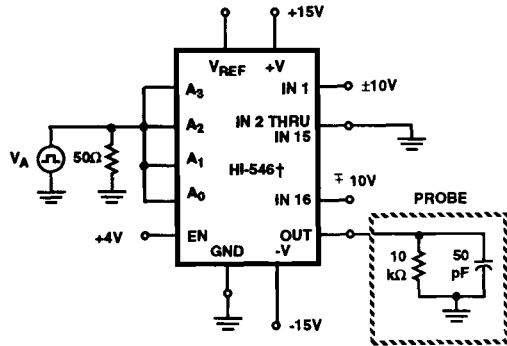


FIGURE 6A. ACCESS TIME vs LOGIC LEVEL (HIGH)

FIGURE 6. ACCESS TIME



† Similar connection for HI-547/HI-548/HI-549

FIGURE 6B. ACCESS TIME TEST CIRCUIT

## Switching Waveforms

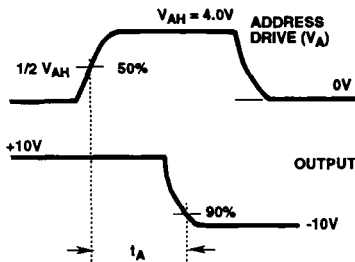


FIGURE 7A. ACCESS TIME MEASUREMENT

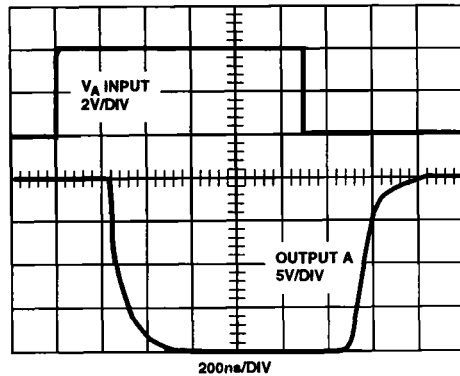
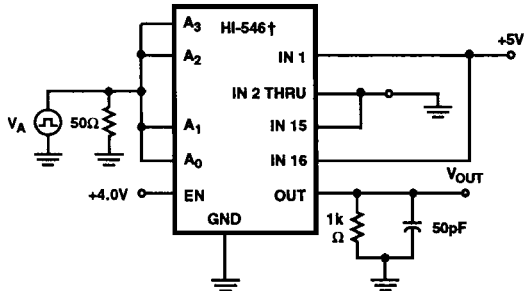


FIGURE 7B. ACCESS TIME WAVEFORMS

FIGURE 7. ACCESS TIME †

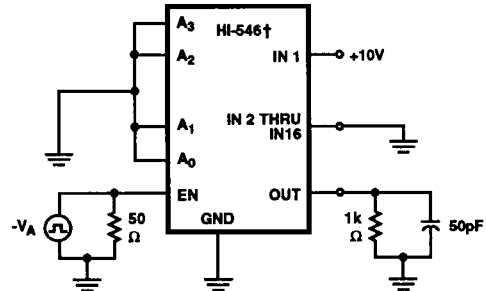
† Refer to Figure 6B for Test Circuit

Switching Waveforms (Continued)



† Similar connection for HI-547/HI-548/HI-549

FIGURE 8A. BREAK-BEFORE-MAKE DELAY TEST CIRCUIT



† Similar connection for HI-547/HI-548/HI-549

FIGURE 9A. ENABLE DELAY TEST CIRCUIT

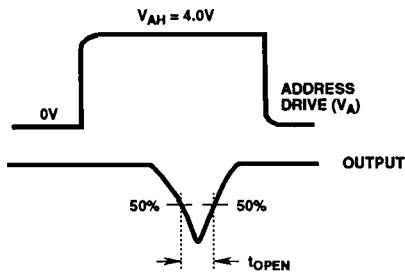


FIGURE 8B. BREAK-BEFORE-MAKE DELAY MEASUREMENT

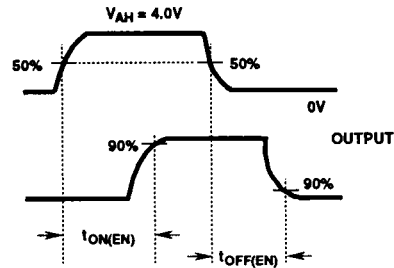


FIGURE 9B. ENABLE DELAY MEASUREMENTS

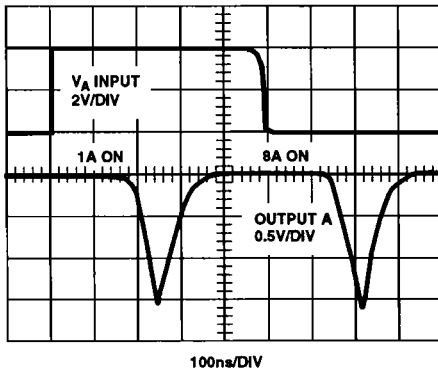


FIGURE 8C. BREAK-BEFORE-MAKE DELAY WAVEFORMS

FIGURE 8. BREAK-BEFORE-MAKE DELAY ( $t_{OPEN}$ )

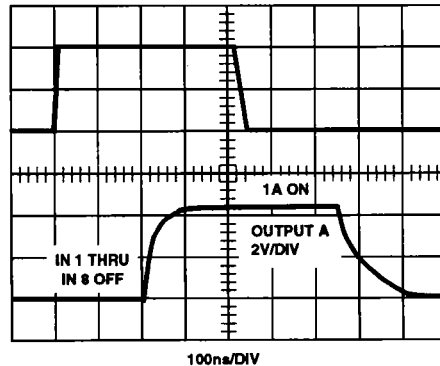


FIGURE 9C. ENABLE DELAY WAVEFORMS

FIGURE 9. ENABLE DELAY ( $t_{ON(EN)}$ ,  $t_{OFF(EN)}$ )

Truth Tables

HI-546

| A <sub>3</sub> | A <sub>2</sub> | A <sub>1</sub> | A <sub>0</sub> | EN | "ON" CHANNEL |
|----------------|----------------|----------------|----------------|----|--------------|
| X              | X              | X              | X              | L  | None         |
| L              | L              | L              | L              | H  | 1            |
| L              | L              | L              | H              | H  | 2            |
| L              | L              | H              | L              | H  | 3            |
| L              | L              | H              | H              | H  | 4            |
| L              | H              | L              | L              | H  | 5            |
| L              | H              | L              | H              | H  | 6            |
| L              | H              | H              | L              | H  | 7            |
| L              | H              | H              | H              | H  | 8            |
| H              | L              | L              | L              | H  | 9            |
| H              | L              | L              | H              | H  | 10           |
| H              | L              | H              | L              | H  | 11           |
| H              | L              | H              | H              | H  | 12           |
| H              | H              | L              | L              | H  | 13           |
| H              | H              | L              | H              | H  | 14           |
| H              | H              | H              | L              | H  | 15           |
| H              | H              | H              | H              | H  | 16           |

HI-548

| A <sub>2</sub> | A <sub>1</sub> | A <sub>0</sub> | EN | "ON" CHANNEL |
|----------------|----------------|----------------|----|--------------|
| X              | X              | X              | L  | None         |
| L              | L              | L              | H  | 1            |
| L              | L              | H              | H  | 2            |
| L              | H              | L              | H  | 3            |
| L              | H              | H              | H  | 4            |
| H              | L              | L              | H  | 5            |
| H              | L              | H              | H  | 6            |
| H              | H              | L              | H  | 7            |
| H              | H              | H              | H  | 8            |

HI-549

| A <sub>1</sub> | A <sub>0</sub> | EN | "ON" CHANNEL PAIR |
|----------------|----------------|----|-------------------|
| X              | X              | L  | None              |
| L              | L              | H  | 1                 |
| L              | H              | H  | 2                 |
| H              | L              | H  | 3                 |
| H              | H              | H  | 4                 |

HI-547

| A <sub>2</sub> | A <sub>1</sub> | A <sub>0</sub> | EN | "ON" CHANNEL PAIR |
|----------------|----------------|----------------|----|-------------------|
| X              | X              | X              | L  | None              |
| L              | L              | L              | H  | 1                 |
| L              | L              | H              | H  | 2                 |
| L              | H              | L              | H  | 3                 |
| L              | H              | H              | H  | 4                 |
| H              | L              | L              | H  | 5                 |
| H              | L              | H              | H  | 6                 |
| H              | H              | L              | H  | 7                 |
| H              | H              | H              | H  | 8                 |

## Die Characteristics

### DIE DIMENSIONS:

83.9 mils x 159 mils x 19 mils

### METALLIZATION:

Type: CuAl

Thickness:  $16\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

### GLASSIVATION:

Type: Nitride Over Silox

Nitride Thickness:  $3.5\text{k}\text{\AA} \pm 1\text{k}\text{\AA}$

Silox Thickness:  $12\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

### WORST CASE CURRENT DENSITY:

$1.4 \times 10^5 \text{A/cm}^2$

### TRANSISTOR COUNT:

HI-546: 485

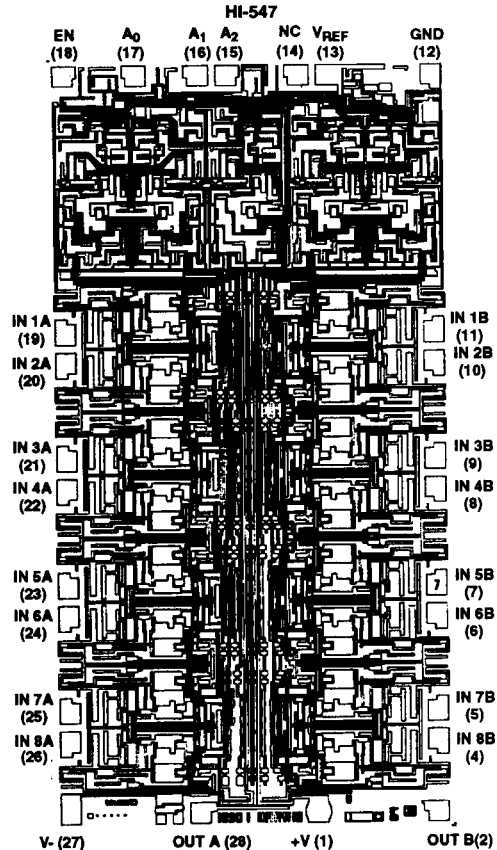
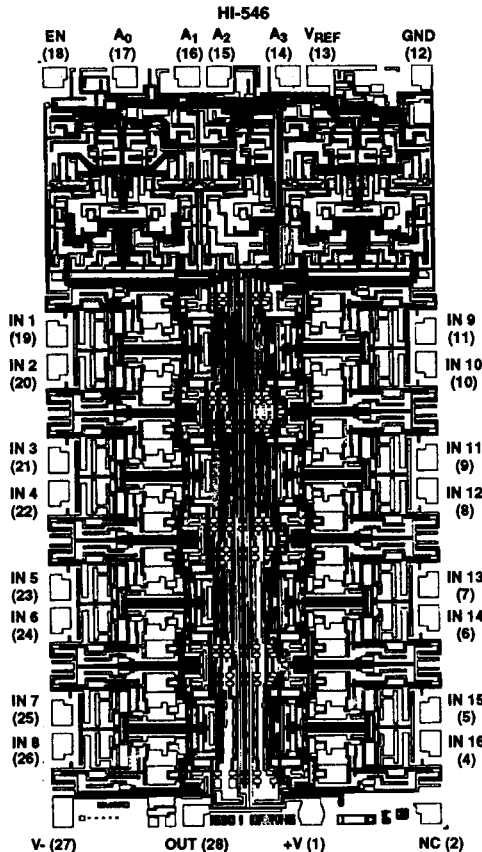
HI-547: 485

### PROCESS: CMOS-DI

### SUBSTRATE POTENTIAL †: $-V_{\text{SUPPLY}}$

† The substrate appears resistive to the  $-V_{\text{SUPPLY}}$  terminal, therefore it may be left floating (insulating Die Mount) or it may be mounted on a conductor at  $-V_{\text{SUPPLY}}$  potential.

## Metallization Mask Layout



## Die Characteristics

### DIE DIMENSIONS:

83 mils x 108 mils x 19 mils

### METALLIZATION:

Type: CuAl

Thickness:  $16\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

### GLASSIVATION:

Type: Nitride Over Silox

Nitride Thickness:  $3.5\text{k}\text{\AA} \pm 1\text{k}\text{\AA}$

Silox Thickness:  $12\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

### WORST CASE CURRENT DENSITY:

$1.4 \times 10^5 \text{A/cm}^2$

### TRANSISTOR COUNT:

HI-548: 253

HI-549: 253

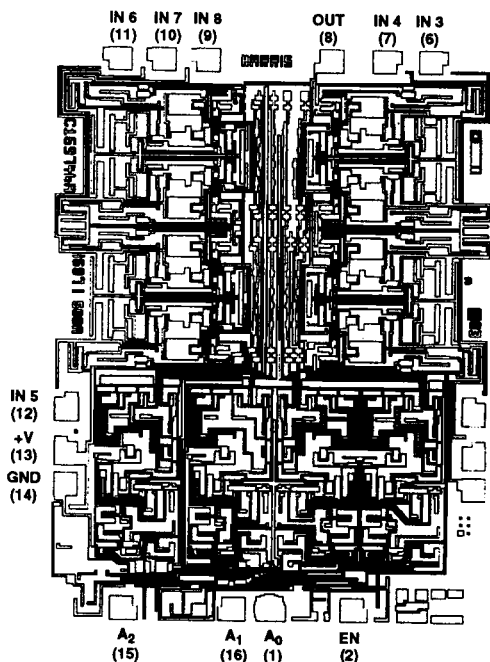
### PROCESS: CMOS-DI

### SUBSTRATE POTENTIAL†: $-V_{\text{SUPPLY}}$

† The substrate appears resistive to the  $-V_{\text{SUPPLY}}$  terminal, therefore it may be left floating (Insulating Die Mount) or it may be mounted on a conductor at  $-V_{\text{SUPPLY}}$  potential.

## Metallization Mask Layout

HI-548



HI-549

